# Speech network for telephones BA8216

The BA8216 is a speech network IC which possesses the basic functions required for handset communications. In addition to amplifying signals from a transmitter and sending them to a telephone line, it also amplifies only reception signals from a telephone line and drives the receiver.

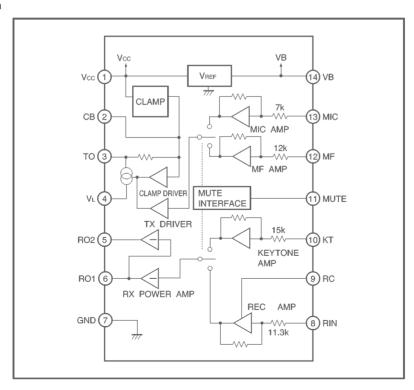
### Applications

Telephones and telephone equipment

### Features

- 1) Basic speech network functions built in.
  - · Handset transmit and receive circuits
  - DTMF transmit circuit
  - · Key tone input circuit
  - · Mute control and side tone masking circuits
- 2) Can be used with  $1.3 k\Omega$  loop circuit resistance and  $100\Omega$  telephone resistance.
- A BTL circuit is used for reception output, providing a wide dynamic range which enables use of a ceramic receiver.
- 4) Few external components required.
- 5) 14-pin DIP package.

### Block diagram



# ●Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Applied voltage	V∟	18	V
Current dissipation	l <sub>L</sub>	135	mA
Power dissipation	Pd	900*	mW
Operating temperature	Topr	<b>−25~+75</b>	°C
Storage temperature	Tstg	<b>−55∼</b> +125	°C

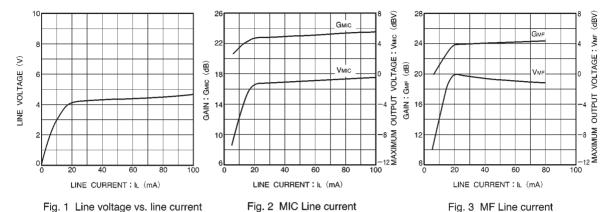
<sup>\*</sup> Reduced by 9 mW for each increase in Ta of 1°C over 25°C.

ullet Electrical characteristics (unless otherwise noted, Ta = 25 $^{\circ}$ C, S<sub>1</sub> = 1, S<sub>2</sub> =1, f = 1kHz, BPF = 400Hz to 30kHz)

Parameter		Symbol	Min.	Тур.	Max.	Unit	IL (mA)	Conditions	Measurement circuit		
Line voltage (20)			V <sub>L20</sub>	3.8	4.15	4.5	٧	20			
Line voltage (120)			VL120	4.1	4.6	5.5	٧	120		Fig.11	
Input high level voltage			Vıн	0.8	_	_	٧	40	S <sub>2</sub> =2		
Input low level voltage			VIL	_	_	0.5	٧	40	S <sub>2</sub> =2		
Input high level current		Ін	100	200	300	μΑ	40	S <sub>2</sub> =2, V <sub>IH</sub> =4V			
Electromagnetic	و	Gain	GRD	-13.8	-10.8	-7.8	dB	40	V⊤=20dBV	Fig.12	
	Receive	Maximum output	V <sub>RD</sub>	-19	-15	_	dBV	20	THD=5%		
	B.	Input impedance	ZRIN	8.3	11.3	14.3	kΩ	40			
		Gain	Gктр	10.5	13.5	16.5	dB	40	S <sub>2</sub> =3, V <sub>KT</sub> =-40dBV	Fig.12	
	KT	Maximum output	VKTD	-19	<b>—</b> 15	_	dBV	20	S <sub>2</sub> =3, THD=5%		
		Input impedance	Zĸт	11	15	19	kΩ	40			
	/e	Gain	GRP	0.9	3.9	6.9	dB	40	$S_1=2, V_T=-20dBV$	Fig.12	
	Receive	Maximum output	VRP	1	5	_	dBV	20	S <sub>1</sub> =2, THD=5%		
ric tr	l œ	Input impedance	ZRIN	8.3	11.3	14.3	kΩ	40			
Piezoelectric		Gain	Gктр	25.1	28.1	31.1	dB	40	S <sub>1</sub> =2, S <sub>2</sub> =3 V <sub>KT</sub> =-40dBV	Fig.12	
	кт	Maximum output	Vктр	1	5	_	dBV	20	S <sub>1</sub> =2, S <sub>2</sub> =3 THD=5%		
		Input impedance	Zĸτ	11	15	19	kΩ	40			
		Gain	Gмic	19.6	22.6	25.6	dB	40	V <sub>M</sub> =-40dBV	Fig.13	
	міс	Maximum output	Vміс	0	4	_	dBV	20	THD=5%		
ä		Input impedance	Zмic	5	7	9	kΩ	40			
Transmit	MF	Gain	Gмғ	21.1	24.1	27.1	dB	40	S <sub>2</sub> =3, V <sub>D</sub> =-40dBV	Fig.13	
-		Maximum output	VMF	0	4	_	dBV	15	S <sub>2</sub> =3, THD=5%		
		Input impedance	ZMF	9	12	15	kΩ	40			
Mute ratio *			MRRD	30	35	_	dB	40	V <sub>T</sub> =-20dBV S <sub>2</sub> =1→3	- Fig.12	
			MRRP	30	35	_	dB	40	V <sub>T</sub> =-20dBV S <sub>2</sub> =1→3, S <sub>1</sub> =2		
			МВміс	60	67	_	dB	40	V <sub>M</sub> =-40dBV S <sub>2</sub> =1→3	- Fig.13	
			MRMF	60	67	_	dB	40	V <sub>D</sub> =-40dBV S <sub>2</sub> =3→1		
			∆Grd	_	-6	_	dB	_	See Fig. 14	Fig.14	
Attenuation during branch		ΔGRP	_	-5	_	dB	_	See Fig. 14			
			Δ С міс	_	-15	_	dB	_	See Fig. 14		
Noise level			NRD	_	<b>—75</b>	_	dBV	120	V <sub>T</sub> =0	Fig.12	
			NRP	_	-73	_	dBV	120	S <sub>1</sub> =2, V <sub>T</sub> =0		
			Иміс	_	<b>-74</b>	_	dBV	120	V <sub>M</sub> =0	Fig.13	
			NMF	_	<b>—71</b>	_	dBV	120	S <sub>2</sub> =3, V <sub>D</sub> =0		

<sup>\*</sup> When using 1 kHz bandpass filter

### Electrical characteristic curves



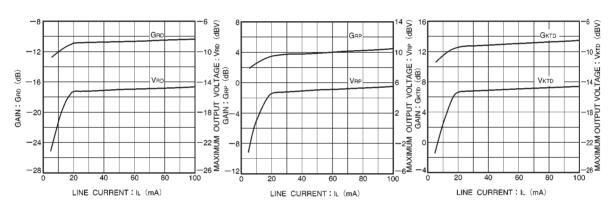


Fig. 4 Electromagnetic receiving Line current

Fig. 1 Line voltage vs. line current

Fig. 5 Piezoelectric receiving Line current

Fig. 6 Electromagnetic KT Line current

Fig. 3 MF Line current

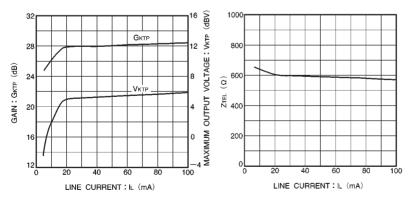


Fig. 7 Piezoelectric KT Line current

Fig. 8 AC impedance Line current

### Measurement circuits

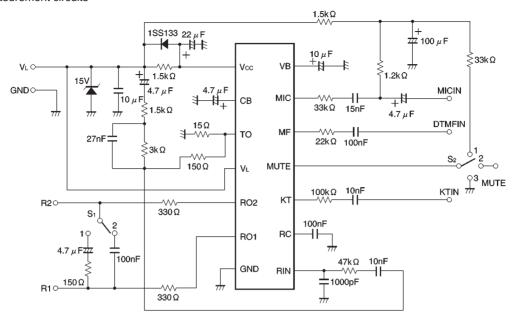


Fig. 9 Basic measurement circuit

ROHM

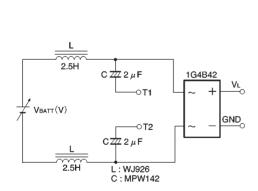


Fig. 10 Trunk circuit

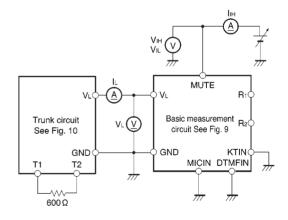


Fig. 11 DC characteristics measurement circuit

Communication ICs BA8216

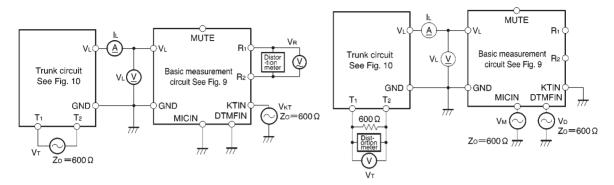


Fig. 12 Reception system measurement circuit

Fig. 13 Transmission system measurement circuit

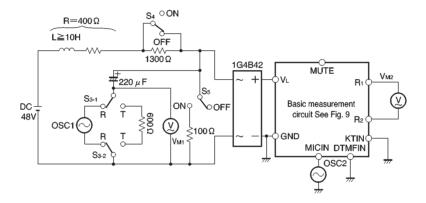


Fig. 14 Branch measurement circuit

### Measurement method (MUTE = HIGH)

- (1) Reception
- 1) Set  $S_3$  to R and  $S_4$  and  $S_5$  to OFF, and input a 1kHz signal from OSC1. Adjust to -10dBV if  $V_{M2}$  is piezoelectric, and to -30dBV if  $V_{M2}$  is electromagnetic.
- 2) With S<sub>4</sub> OFF and S<sub>5</sub> ON, record the output level of  $V_{M2}$  and note this value as  $V_{M2}$  (2).
- 3) With  $S_4$  ON and  $S_5$  ON, measure the output level of  $V_{M2}$ , and note this value as  $V_{M2}$  (3).

 $\Delta G_R = 20log (V_{M2} (3)/V_{M2}(2))$ 

- (2) Transmission
- 1) Set  $S_3 = T$  and  $S_4$  and  $S_5$  to OFF, input a 1kHz signal from OSC2, and adjust so that  $V_{M1}$  is -10dBV.
- 2) With  $S_4$  OFF and  $S_5$  ON, record the output level of  $V_{M1}$  and note this value as  $V_{M1}$  (2).
- 3) With  $S_4$  ON and  $S_5$  ON, measure the output level of  $V_{M1}$ , and note this value as  $V_{M1}$  (3).

 $\Delta$ GMIC = 20log (V<sub>M1</sub> (3)/V<sub>M1</sub>(2))

S<sub>3</sub>: Send and receive switch (reception side)

S<sub>4</sub>: ON/OFF switch for line resistance (1300 $\Omega$ ) (OFF)

S<sub>5</sub>: ON/OFF switch for parallel resistance (100 $\Omega$ ) (OFF)

### Circuit opperation

The BA8216 carries out the following basic operations.

(1) Handset talk and receive

The BA8216 receives a voice signal from a telephone line and outputs it to a handset speaker. It also takes a voice signal from the handset microphone and outputs it to the telephone line.

(2) DTMF send and key tone input

The BA8216 has a mute switch which can be switched between a "handset send and receive" mode and a "DTMF send and key tone input" mode by an external logic signal. In the "DTMF send and key tone input" mode, it transmits DTMF signals from the dial pad to the telephone line, and key tones to the handset receiver.

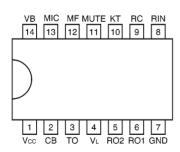
### Operation notes

The maximum power dissipation for the BA8216 is 900mW. Since the maximum power dissipation varies with temperature, the product of the applied voltage V<sub>L</sub> and the total current drawn by the IC, after factoring in the temperature, should not exceed the maximum dissipation.

# Pin descriptions

Pin No.	Symbol	Name	Function
1	Vcc	Internal power supply pin	Internal power supply pin. Power is supplied from V <sub>L</sub> through resistor R <sub>101</sub> , and is smoothed by capacitor C <sub>101</sub> .
2	СВ	Bypass capacitor connector pin	This is used to connect an AC bypass capacitor to form a DC feedback loop for stabilizing the DC potential of the VL pin.
3	то	Transmit/power dissipation resistor connector pin	This is connected between the power dissipation resistor $R_{105}$ and the GND,to eliminate unnecessary power consumption. At the same time, $R_{105}$ determines the gain of the final output stage of the transmission driver. $R_{104}$ and $R_{105}$ form two legs of the side tone suppression bridge, which is also connected to this pin.
4	VL	V <sub>L</sub> pin	This is the power supply pin. The transmit signal is output to the telephone line through this pin. It is connected to the (+) side of the diode bridge.
5	RO <sub>2</sub>	Receive output pin	When a piezoelectric receiver is used, connect a 330- protection resistor $R_{191}$ to this pin. When a dynamic receiver is used, $R_{191}$ may be $0\Omega$ .
6	RO <sub>1</sub>	Receive output pin	When a piezoelectric receiver is used, connect a 330- protection resistor R <sub>106</sub> to this pin. C <sub>191</sub> is shorted. When a dynamic receiver is used, a 4.7 $\mu$ F DC blocking capacitor (C <sub>191</sub> ) is connected in series with the 680 $\Omega$ resistor (R <sub>106</sub> ) to this pin.
7	GND	Ground pin	This pin has the lowest potential on the IC. It is connected to the (—) pin of the diode bridge.
8	RIN	Receive input pin	After passing through a side tone suppression circuit, the receive signal frothe telephone line is input to this pin.
9	RC	Receive amplifier bypass capacitor pin	This is connected to the AC bypass capacitor of the reception amplifier.
10	KT	Key tone input pin	When the MUTE pin is low, key tone signals input on this pin are transmitted to the handset speaker.
11	MUTE	Mute input pin	When this is high, hand-set transmission is normal. When this is low, DTMF signals applied at the MF input are output to the telephone line, and key tones applied to the KT pin are transmitted to the hand receiver.
12	MF	DTMF signal input pin	When the MUTE pin is low, DTMF signals input to this pin are output to the telephone line.
13	MIC	Microphone input pin	Used to input signals from the microphone.
14	VB	Bias pin	This is the IC internal bias pin. It is connected to the bypass capacitor C <sub>111</sub> .

# Pin assignments



# Mute control input logic

MUTE	MIC AMP	MF AMP	REC AMP	KT AMP	
Н	ON	OFF	ON	OFF	
L	OFF	ON	OFF	ON	

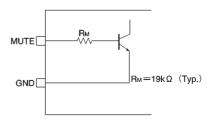


Fig. 15 Mute input equivalent circuit

## Application example

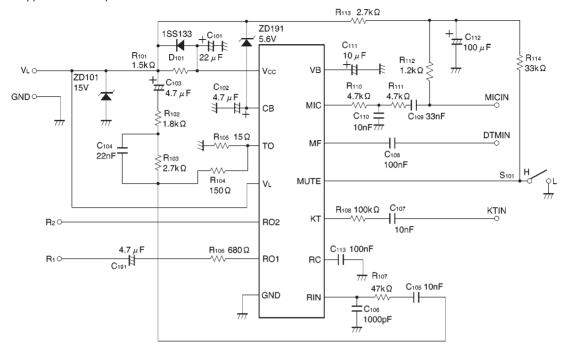


Fig. 16

# External dimensions (Units: mm)

